



ZK1200A-C FAST RECOVERY DIODE

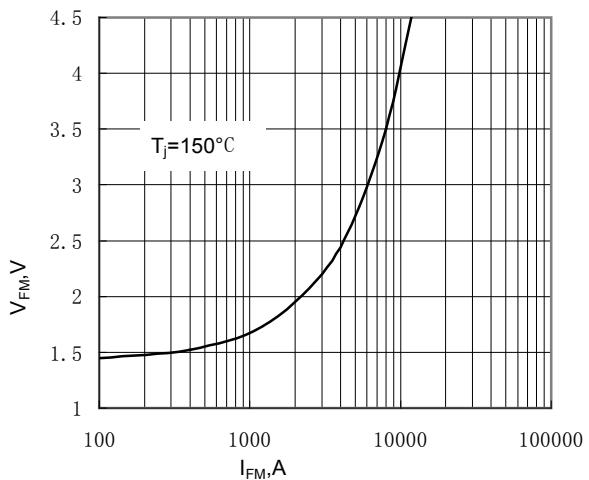
Features

- Low forward voltage drop
- Soft recovery
- Hermetic metal cases with ceramic insulators
- Application**
- Inverters and choppers
- AC. motor control
- Snubber and free-wheeling diodes

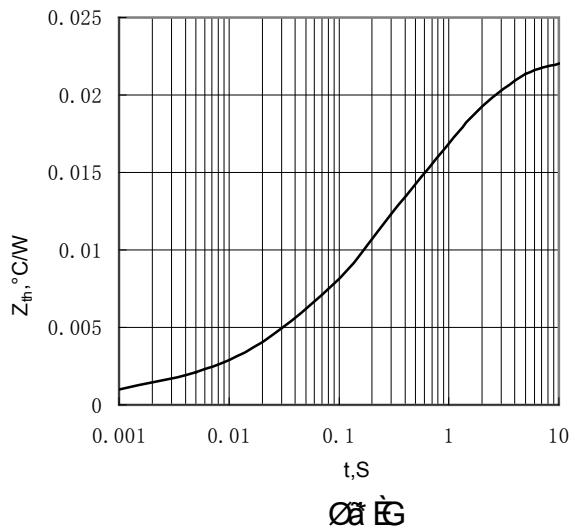
I _{F(AV)}	1200A
V _{RRM}	1100-2000V
I _{FSM}	15KA
t _{rr}	4.0 μ s

SYMBOL	PARAMETERS	TESTING CONDITION	T _j (°C)	VALUE S	UNIT
Current Ratings	I _{F(AV)}	average forward current	180° half sine wave 50Hz Double side cooled, Ths=92°C	150	1200 A
	I _{F(AV)}	average forward current	180° half sine wave 50Hz Double side cooled, Ths=55°C	150	1715 A
	I _{FSM}	Surge forward current	10ms half sine wave VR=0.6VRRM	150	15 KA
	I ² t	I ² t for fusing coordination		150	1100 KA ² S
Characteristics	V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{RRM} +100V	150	1100-2000 V
	I _{RRM}	Repetitive peak current	V _{RM} = V _{RRM}	150	Max.80 Ma
	V _{FM}	Peak on-state voltage	I _{TM} =3000A, F=24KN	25	Max.2.8 V
	V _{FO}	Threshold voltage		150	Max.1.42 V
	r _F	Forward slop resistance			Max.0.26 mΩ
	I _{rm}	Reverse recovery current	I _{TM} =1000A, t _p =1000μs, di/dt=-20A/μs, Vr=50V	100	Typ.114 A
	t _{rr}	Reverse recovery time			Typ.4.0 μs
	Q _{rr}	Recovery charge			Typ.228 μc Max.250
Thermal & Mechanical Date	R _{th(j-h)}	Thermal resistance Junction to heat sink	At 180° sine, double side cooled mounting force 24KN		0.022 °C/W
	F _m	Mounting force			19-26 KN
	T _{stg}	Stored temperature			-40-160 °C
	W _t	Weight			470 g

Peak forward Voltage Vs. Peak forward Current



Max. junction To heatsink Thermal Impedance Vs. Time



Surge Current Vs. Cycles

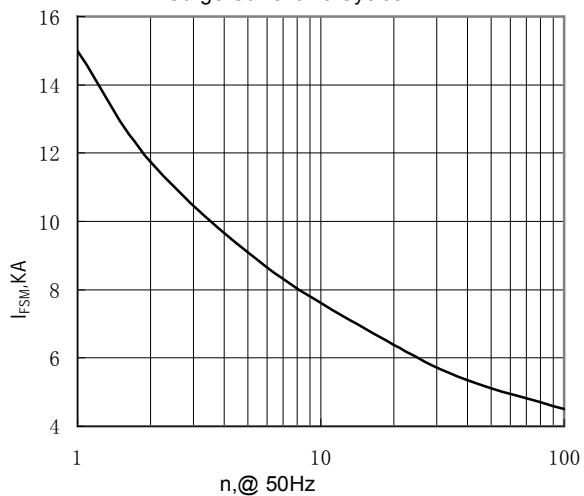


图 4

I²t Vs. Time

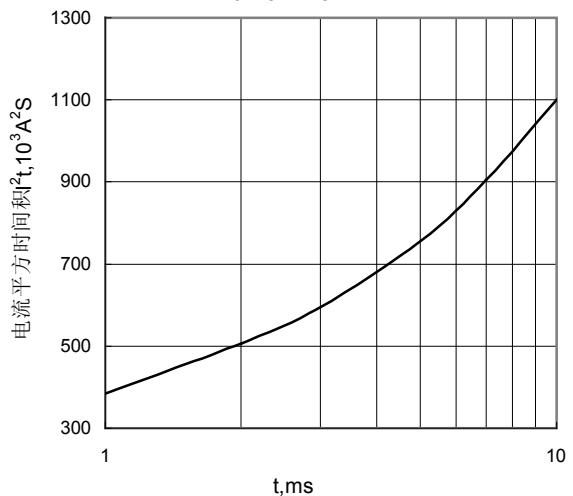


图 5

F lo gpuskpu<

C20

